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Outline

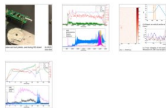
Abstract

Keywords

1. Introduction
 2. Semiconductor detectors
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Runaway electrons diagnostics using segmented semiconductor detectors

Peter Svihra ^{a, R. B.}, David Bren ^a, Andrea Casolari ^b, Jaroslav Cerovsky ^{a, b}, Praveesh Dhyan ^a, Michal Famik ^{a, b}, Ondrej Ficker ^{a, b}, Miroslav Havranek ^a, Martin Hejmanek ^a, Zdenko Janoska ^a, Vladimir Kafka ^a, Petr Kulhanek ^b, Vladimir Linhart ^a, Eva Macusova ^b, Maria Marcisovska ^a, Michal Marcisovsky ^a, Jan Mlynar ^{a, b}, Gordon Neue ^a ... Vladimir Weinzettl ^b

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Abstract

A novel application of strip and pixel silicon radiation detectors for study and characterization of run-away electron events in tokamaks is presented. Main goal was to monitor runaway electrons both directly and indirectly. The strip detector was placed inside the tokamak vacuum chamber in order to monitor the run-away electrons directly. Whereas the pixel detector was placed outside the tokamak chamber behind a pin hole for monitoring the run-away electrons indirectly via radiation produce by interaction of the electrons with the plasma facing material. Results obtained using the silicon detectors are compared with

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